International **TOR** Rectifier

# IR3093PbF

DATA SHEET

# 3 PHASE OPTERON, ATHLON, OR VR10.X CONTROL IC

#### DESCRIPTION

The IR3093 Control IC provides a full featured, cost effective, single chip solution to implement robust power conversion solutions for three different microprocessor families; 1) AMD's Opteron, 2) AMD's Athlon or 3) Intel's VR-10.X family of processors. The user can select the appropriate VID range with a single pin. Control and 3 phase Gate Drive functions are integrated into a single cost effective IC. In addition to CPU power, IR3093 offers a compact, efficient solution for high current POL converters.

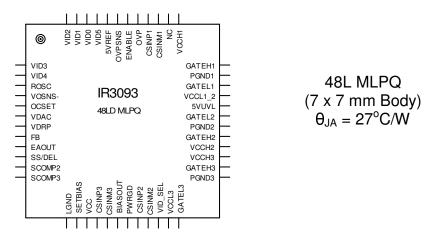
#### **FEATURES**

- 5 bit or 6 bit VID with 0.5% overall system accuracy
- Selectable VID Code for AMD Opteron or Athlon or Intel VR10.X
- Programmable Slew Rate response to "On-the-Fly" VID Code Changes
- 3A GATELX Pull Down Drive Capability
- Programmable 100KHz to 540KHz oscillator
- Programmable Voltage Positioning (can be disabled)
- Programmable Softstart
- Programmable Hiccup Over-Current Protection with Delay to prevent false triggering
- Simplified Powergood provides indication of proper operation and avoids false triggering
- Operates up to 21V input with 7.9V Under-Voltage Lockout
- 5V UVL with 4.36V Under-Voltage Lockout threshold
- Adjustable Voltage, 150mA Bias Regulator provides MOSFET Drive Voltage
- Enable Input
- OVP Flag Output detects high side fet short at powerup
- Pin compatible with IR3092, 2-phase PWM Control IC
- Available 48L MLPQ package

#### **ORDERING INFORMATION**

| Device       | Order Quantity   |
|--------------|------------------|
| IR3093MTRPbF | 3000 per Reel    |
| IR3093MPbF   | 100 piece strips |

#### **PACKAGE INFORMATION**



# **PIN DESCRIPTION**

| PIN# | PIN SYMBOL | PIN DESCRIPTION  |
|------|------------|--|
| 1    | VID3       | Inputs to VID D to A Converter   |
| 2    | VID4       | Inputs to VID D to A Converter   |
| 3    | ROSC       | Connect a resistor to VOSNS- to program oscillator frequency and FB, OCSET, BBFB, and VDAC bias currents   |
| 4    | VOSNS-     | Remote Sense Input. Connect to ground at the Load.   |
| 5    | OCSET      | Programs the hiccup over-current threshold through an external resistor tied to VDAC and an internal current source.   |
| 6    | VDAC       | Regulated voltage programmed by the VID inputs. Current Sensing and Over Current Protection are referenced to this pin. Connect an external RC network to VOSNS- to program Dynamic VID slew rate.   |
| 7    | VDRP       | Buffered IIN signal. Connect an external RC network to FB to program converter output impedance  |
| 8    | FB         | Inverting input to the Error Amplifier. Converter output voltage is offset from the VDAC voltage through an external resistor connected to the converter output voltage at the load and an internal current source. Bias current is a function of ROSC. Also OVP sense |
| 9    | EAOUT      | Output of the Error Amplifier  |
| 10   | SS/DEL     | Controls Converter Softstart, Power Good, and Over-Current Timing. Connect an external capacitor to LGND to program the timing.  |
| 11   | SCOMP2     | Compensation for the Current Share control loop. Connect a capacitor to ground to set the control loop's bandwidth. Phase 2 is forced to match phase 1's current.  |
| 12   | SCOMP3     | Compensation for the Current Share control loop. Connect a capacitor to ground to set the control loop's bandwidth. Phase 3 is forced to match phase 1's current.  |
| 13   | LGND       | Local Ground and IC substrate connection   |
| 14   | SETBIAS    | External resistor to ground sets voltage at BIASOUT pin. Bias current is a function of ROSC.   |
| 15   | VCC        | Power for internal circuitry and source for BIASOUT regulator  |
| 16   | CSINP3     | Non-inverting input to the Phase 3 Current Sense Amplifier.  |
| 17   | CSINM3     | Inverting input to the Phase 3 Current Sense Amplifier.  |
| 18   | BIASOUT    | 200mA open-looped regulated voltage set by SETBIAS for GATE drive bias.  |
| 19   | PWRGD      | Open Collector output that drives low during Softstart or any fault condition. Connect external pull-up.   |
| 20   | CSINP2     | Non-inverting input to the Phase 2 Current Sense Amplifier.  |
| 21   | CSINM2     | Inverting input to the Phase 2 Current Sense Amplifier.  |
| 22   | VID_SEL    | Ground Selects VR10.X VID, Float Selects OPTERON VID, VCC Selects ATHLON VID   |
| 23   | VCCL3      | Power for Phase 3 Low-Side Gate Driver.  |
| 24   | GATEL3     | Phase 3 Low-Side Gate Driver Output and input to GATEH3 non-overlap comparator.  |
| 25   | PGND3      | Return for Phase 3 Gate Drivers  |
| 26   | GATEH3     | Phase 3 High-Side Gate Driver Output and input to GATEL3 non-overlap comparator.   |
| 27   | VCCH3      | Power for Phase 3 High-Side Gate Driver  |
| 28   | VCCH2      | Power for Phase 2 High-Side Gate Driver  |
| 29   | GATEH2     | Phase 2 High-Side Gate Driver Output and input to GATEL2 non-overlap comparator.   |
| 30   | PGND2      | Return for Phase 2 Gate Drivers  |
| 31   | GATEL2     | Phase 2 Low-Side Gate Driver Output and input to GATEH2 non-overlap comparator.  |
| 32   | 5VUVL      | Can be used to monitor the driver supply voltage or 5V supply voltage when converting from 5V. An under voltage condition initiates Soft Start.  |
| 33   | VCCL1_2    | Power for Phase 1 and 2 Low-Side Gate Drivers.   |
| 34   | GATEL1     | Phase 1 Low-Side Gate Driver Output and input to GATEH1 non-overlap comparator.  |
| 35   | PGND1      | Return for Phase 1 Gate Drivers  |
| 36   | GATEH1     | Phase 1 High-Side Gate Driver Output and input to GATEL1 non-overlap comparator.   |
| 37   | VCCH1      | Power for Phase 1 High-Side Gate Driver  |
| 38   | NC         | Not connected  |
| 39   | CSINM1     | Inverting input to the Phase 1Current Sense Amplifier.   |
| 40   | CSINP1     | Non-inverting input to the Current Sense Amplifier.  |
| 41   | OVP        | Output that drives high during an Over-Voltage condition.  |
| 42   | ENABLE     | Enable Input. A logic low applied to this pin puts the IC into Fault mode.   |
| 43   | OVPSNS     | Dedicated output voltage sense pin for Over Voltage Protection.  |
| 44   | 5VREF      | Compensation for internal voltage reference rail.  |
| 45   | VID5       | Inputs to VID D to A Converter   |
| 46   | VID0       | Inputs to VID D to A Converter   |
| 47   | VID1       | Inputs to VID D to A Converter   |
| 48   | VID2       | Inputs to VID D to A Converter   |

# ABSOLUTE MAXIMUM RATINGS

Operating Junction Temperature......150°C Storage Temperature Range.....-65°C to 150°C

| PIN | NAME    | VMAX | VMIN                    | ISOURCE                | ISINK                  |
|-----|---------|------|-------------------------|------------------------|------------------------|
| 1   | VID3    | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 2   | VID4    | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 3   | ROSC    | 30V  | -0.5V                   | 1mA                    | 1mA                    |
| 4   | VOSNS-  | 0.5V | -0.5V                   | 10mA                   | 10mA                   |
| 5   | OCSET   | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 6   | VDAC    | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 7   | VDRP    | 30V  | -0.3V                   | 5mA                    | 5mA                    |
| 8   | FB      | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 9   | EAOUT   | 10V  | -0.3V                   | 10mA                   | 20mA                   |
| 10  | SS/DEL  | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 11  | SCOMP2  | 30V  | -0.3V                   | 5mA                    | 5mA                    |
| 12  | SCOMP3  | 30V  | -0.3V                   | 5mA                    | 5mA                    |
| 13  | LGND    | n/a  | n/a                     | 50mA                   | 1mA                    |
| 14  | SETBIAS | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 15  | VCC     | 30V  | -0.3V                   | 1mA                    | 250mA                  |
| 16  | CSINP3  | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 17  | CSINM3  | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 18  | BIASOUT | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 19  | PWRGD   | 30V  | -0.3V                   | 1mA                    | 20mA                   |
| 20  | CSINP2  | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 21  | CSINM2  | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 22  | VID_SEL | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 23  | VCCL3   | 30V  | -0.3V                   | n/a                    | 3A for 100ns, 200mA DC |
| 24  | GATEL3  | 30V  | -0.3V DC, -2V for 100ns | 3A for 100ns, 200mA DC | 3A for 100ns, 200mA DC |
| 25  | PGND3   | 0.3V | -0.3V                   | 3A for 100ns, 200mA DC | n/a                    |
| 26  | GATEH3  | 30V  | -0.3V DC, -2V for 100ns | 3A for 100ns, 200mA DC | 3A for 100ns, 200mA DC |
| 27  | VCCH3   | 30V  | -0.3V                   | n/a                    | 3A for 100ns, 200mA DC |
| 28  | VCCH2   | 30V  | -0.3V                   | n/a                    | 3A for 100ns, 200mA DC |
| 29  | GATEH2  | 30V  | -0.3V DC, -2V for 100ns | 3A for 100ns, 200mA DC | 3A for 100ns, 200mA DC |
| 30  | PGND2   | 0.3V | -0.3V                   | 3A for 100ns, 200mA DC | n/a                    |
| 31  | GATEL2  | 30V  | -0.3V DC, -2V for 100ns | 3A for 100ns, 200mA DC | 3A for 100ns, 200mA DC |
| 32  | 5VUVL   | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 33  | VCCL1_2 | 30V  | -0.3V                   | n/a                    | 3A for 100ns, 200mA DC |
| 34  | GATEL1  | 30V  | -0.3V DC, -2V for 100ns | 3A for 100ns, 200mA DC | 3A for 100ns, 200mA DC |
| 35  | PGND1   | 0.3V | -0.3V                   | 3A for 100ns, 200mA DC | n/a                    |
| 36  | GATEH1  | 30V  | -0.3V DC, -2V for 100ns | 3A for 100ns, 200mA DC | 3A for 100ns, 200mA DC |
| 37  | VCCH1   | 30V  | -0.3V                   | n/a                    | 3A for 100ns, 200mA DC |
| 38  | NC      | n/a  | n/a                     | n/a                    | n/a                    |
| 39  | CSINM1  | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 40  | CSINP1  | 30V  | -0.3V                   | 250mA                  | 1mA                    |
| 41  | OVP     | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 42  | ENABLE  | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 43  | OVPSNS  | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 44  | 5VREF   | 10V  | -0.3V                   | 10mA                   | 20mA                   |
| 45  | VID5    | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 46  | VID0    | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 47  | VID1    | 30V  | -0.3V                   | 1mA                    | 1mA                    |
| 48  | VID2    | 30V  | -0.3V                   | 1mA                    | 1mA                    |

# ELECTRICAL SPECIFICATIONS

Unless otherwise specified, these specifications apply over: 7.4V  $\leq V_{CC} \leq 21V$ , 4V  $\leq V_{CCLX} \leq 14V$ , 4V  $\leq V_{CCHX} \leq 28V$ ,  $C_{GATEHX} = 3.3nF$ ,  $C_{GATELX} = 6.8nF$ , 0°C  $\leq T_J \leq 125$  °C

| PARAMETER                       | TEST CONDITION  | MIN  | TYP  | MAX  | UNIT |
|---------------------------------|---|------|------|------|------|
| VDAC Reference                  |   |      |      |      |      |
| System Set-Point Accuracy       | $-0.3V \le VOSNS \le 0.3V$ , Connect FB to<br>EAOUT, Measure V(EAOUT) –<br>V(VOSNS-) deviation from Table 1.<br>Applies to all VID codes. |      | 0.5  |      | %    |
| Sink Current                    | $R_{ROSC} = 47k\Omega$ , VDAC=OCSET   | 45   | 53   | 61   | μA   |
| Source Current                  | $R_{ROSC} = 47k\Omega$ , VDAC=OCSET   | 48   | 56   | 64   |      |
| VID Input Threshold, INTEL      | VID_SEL=0, Referenced to VOSNS-   | 0.4  | 0.6  | 0.8  | V    |
| VID Input Threshold, AMD        | VID_SEL=Float, Referenced to VOSNS-   | 1.55 | 1.65 | 1.75 | V    |
| VID_SEL OPTERON<br>Threshold    |   | 1.0  | 1.2  | 1.4  | V    |
| VID_SEL ATHLON Threshold        |   | 3.0  | 3.3  | 3.8  | V    |
| VID_SEL Float Voltage           | Tracks ATHLON threshold   | 2.1  | 2.6  | 3.2  | V    |
| VID_SEL Pull-up Resistance      | V(VID_SEL)<2.1V   | 30   | 50   | 100  | kΩ   |
| VID_SEL Pull-down<br>Resistance | V(VID_SEL)>3.2V   | 60   | 150  | 350  | kΩ   |
| VID Pull-up Current             | VID0-5 = 1V   | 9    | 18   | 27   | μA   |
| VID Float Voltage               | Referenced to LGND  | 4.5  | 4.9  | 5.2  | V    |
| VID = 11111 Fault Blanking      | Delay to PWRGD assertion  | 0.5  | 2.1  | 4.1  | μS   |
| Error Amplifier                 |   |      |      |      |      |
| Input Offset Voltage            | Connect FB to EAOUT, Measure<br>V(EAOUT)-V(VDAC). Applies to all VID<br>codes and -0.3V <vosns-<0.3v. note<br="">2.</vosns-<0.3v.>        | -5   | -1   | 3    | mV   |
| FB Bias Current                 | $R_{ROSC} = 47k\Omega$  | 23.5 | 26.4 | 29.4 | μA   |
| DC Gain                         | Note 1  | 90   | 100  | 105  | dB   |
| Gain-Bandwidth Product          | Note 1  | 4    | 7    |      | MHz  |
| Slew Rate                       | Note 1, 50mV FB signal  |      | 1.25 |      | V/µs |
| Source Current                  | -   | 300  | 430  | 600  | μA   |
| Sink Current                    |   | .75  | 1.1  | 1.5  | mA   |
| Max Voltage                     |   | 4.5  | 4.9  | 5.3  | V    |
| Min Voltage                     |   |      | 50   | 200  | mV   |
| VDRP Buffer Amplifier           |   |      |      |      |      |
| Positioning Offset Voltage      | V(VDRP) – V(VDAC) with<br>CSINMX=CSINPX=0. Note 1.  | -125 | 0    | 125  | mV   |
| Output Voltage Range            |   | 0.2  |      | 3.75 | V    |

| PARAMETER                            | TEST CONDITION   | MIN  | TYP  | MAX   | UNIT       |
|--------------------------------------|--|------|------|-------|------------|
| VDRP Buffer Amplifier cont.          |  |      |      |       |            |
| Source Current                       |  | 4    | 8    | 20    | mA         |
| Sink Current                         |  | 200  | 300  | 650   | μA         |
| Oscillator                           |  |      |      |       | •          |
| Switching Frequency                  | $R_{ROSC} = 47k\Omega$   | 160  | 200  | 240   | kHz        |
| Phase Shift                          | Sequence: GATEH1-GATEH2-GATEH3                                 | 102  | 120  | 138   | 0          |
| BIASOUT Regulator                    |  |      |      |       |            |
| SETBIAS Bias Current                 | $R_{ROSC} = 47k\Omega$   | 94   | 103  | 117.5 | μA         |
| Set Point Accuracy                   | V(SETBIAS)-V(BIASOUT) @ 100mA                                  | 0.1  | 0.25 | 0.55  | V          |
| BIASOUT Dropout Voltage              | I(BIASOUT)=100mA,Threshold when<br>V(SETBIAS)-V(BIASOUT)=0.45V | 1.2  | 1.8  | 2.5   | V          |
| BIASOUT Current Limit                |  | 150  | 250  | 450   | mA         |
| Soft Start and Delay                 |  |      |      |       |            |
| SS/DEL to FB Input Offset<br>Voltage | With FB = 0V, adjust V(SS/DEL) until EAOUT drives high         | 0.8  | 1.1  | 1.8   | V          |
| Charge Current                       |  | 30   | 60   | 90    | μA         |
| Hiccup Discharge Current             |  | 3.5  | 6    | 9     | μA         |
| OC Discharge Current                 |  | 25   | 55   | 70    | μ <b>Α</b> |
| Charge/Discharge Current<br>Ratio    |  | 9    | 10   | 13    | μΑ/μΑ      |
| Charge Voltage                       |  | 3.8  | 4.0  | 4.2   | V          |
| Delay Comparator Threshold           | Relative to Charge Voltage                                     | 190  | 250  | 300   | mV         |
| Discharge Comparator<br>Threshold    |  | 170  | 265  | 350   | mV         |
| Over-Current Comparator              |  |      |      |       |            |
| Input Offset Voltage                 | V(OCSET)-V(VDAC),<br>CSINM=CSINP1=CSINP2=CSINP3,<br>Note 1.    | -125 | 0    | 125   | mV         |
| OCSET Bias Current                   | $R_{ROSC} = 47k\Omega$   | 23.5 | 27   | 29.4  | μA         |
| Max OCSET Set Point                  |  | 3.9  |      |       | V          |
| Under-Voltage Lockout                |  |      |      |       |            |
| VCC Start Threshold                  |  | 7.4  | 7.9  | 8.4   | V          |
| VCC Stop Threshold                   |  | 6.9  | 7.4  | 7.9   | V          |
| VCC Hysteresis                       | Start – Stop   | 400  | 540  | 700   | mV         |
| 5VUVL Start Threshold                |  | 4.05 | 4.36 | 4.55  | V          |
| 5VUVL Stop Threshold                 |  | 3.92 | 4.17 | 4.33  | V          |
| 5VUVL Hysteresis                     | Start – Stop   | 100  | 200  | 250   | mV         |

| PARAMETER                        | TEST CONDITION  | MIN  | TYP  | MAX  | UNIT         |
|----------------------------------|---|------|------|------|--------------|
| PWRGD Output                     |   |      |      |      |              |
| Output Voltage                   | I(PWRGD) = 4mA  |      | 150  | 400  | mV           |
| Leakage Current                  | V(PWRGD) = 5.5V   |      | 0    | 10   | μA           |
| Enable Input                     |   |      |      |      | •            |
| Threshold, INTEL                 | VID_SEL=0, Referenced to VOSNS-   | 0.4  | 0.6  | 0.8  | V            |
| Threshold, AMD                   | VID_SEL=Float, Referenced to VOSNS-   | 1.3  | 1.5  | 1.7  | V            |
| Input Resistance                 |   | 5    | 10   | 20   | kΩ           |
| Pull-up Voltage                  |   | 2.4  | 3.0  | 3.7  | V            |
| Gate Drivers                     |   |      |      |      |              |
| GATEH Rise Time                  | VCCHX = 8V, Measure 1V to 7V transition time. Note 1.   |      | 25   | 50   | ns           |
| GATEH Fall Time                  | VCCHX = 8V, Measure 7V to 1V transition time. Note 1.   |      | 25   | 50   | ns           |
| GATEL Rise Time                  | VCCLX= 8V, Measure 1V to 7V transition time. Note 1.  |      | 50   | 90   | ns           |
| GATEL Fall Time                  | VCCLX= 8V, Measure 7V to 1V transition time. Note 1.  |      | 30   | 60   | ns           |
| High Voltage (AC)                | Measure VCCLX- GATELX or VCCHX - GATEHX, Note 1   |      | 0    | 0.5V | V            |
| Low Voltage (AC)                 | Measure GATELX or GATEHX, Note 1  |      | 0    | 0.5V | V            |
| GATEL low to GATEH high<br>delay | VCCHX = VCCLX= 8V, Measure the time<br>from GATELX falling to 1V to GATEHX<br>rising to 1V. Note 1. | 10   | 25   | 50   | ns           |
| GATEH low to GATEL high delay    | VCCHX = VCCLX= 8V, Measure the time<br>from GATEHX falling to 1V to GATELX<br>rising to 1V. Note 1. | 10   | 25   | 50   | ns           |
| Disable Pull-Down Current        | GATHX or GATELX=2V with VCC = 0V.<br>Measure Gate pull-down current                                 | 20   | 35   | 50   | μA           |
| PWM Comparator                   |   |      |      |      |              |
| Propagation Delay                | Note1   |      | 100  | 150  | ns           |
| Common Mode Input Range          |   |      |      | 4    | V            |
| Internal Ramp Start Voltage      |   | 0.45 | 0.6  | 0.9  | V            |
| Internal Ramp Amplitude          |   | 35   | 50   | 65   | mV /<br>%DTC |
| Current Sense Amplifier          |   |      |      |      |              |
| CSINPX Bias Current              |   | -1   | 0    | 1    | μA           |
| CSINMX Bias Current              |   | -1   | 0    | 1    | μA           |
| Input Current Offset Ratio       |   | 0.25 | 1    | 2    | μΑ/μΑ        |
| Average Input Offset Voltage     | (VDRP-VDAC)/GAIN with CSINX=0. Note1  | -5   | 0    | 5    | mV           |
| Offset Voltage Mismatch          | Monitor I(SCOMPX), Note1.   | -5   | 0    | 5    | mV           |
| Gain at T <sub>J</sub> = 25 °C   |   | 22   | 23.5 | 25   | V/V          |
| Gain at T <sub>J</sub> = 125 °C  |   | 18.5 | 20.4 | 21.5 | V/V          |
| Gain Mismatch                    | Note 1.   | -1   | 0    | 1    | V/V          |
| Differential Input Range         |   | -25  |      | 75   | mV           |
| Common Mode Input Range          |   | 0    |      | 2.8  | V            |

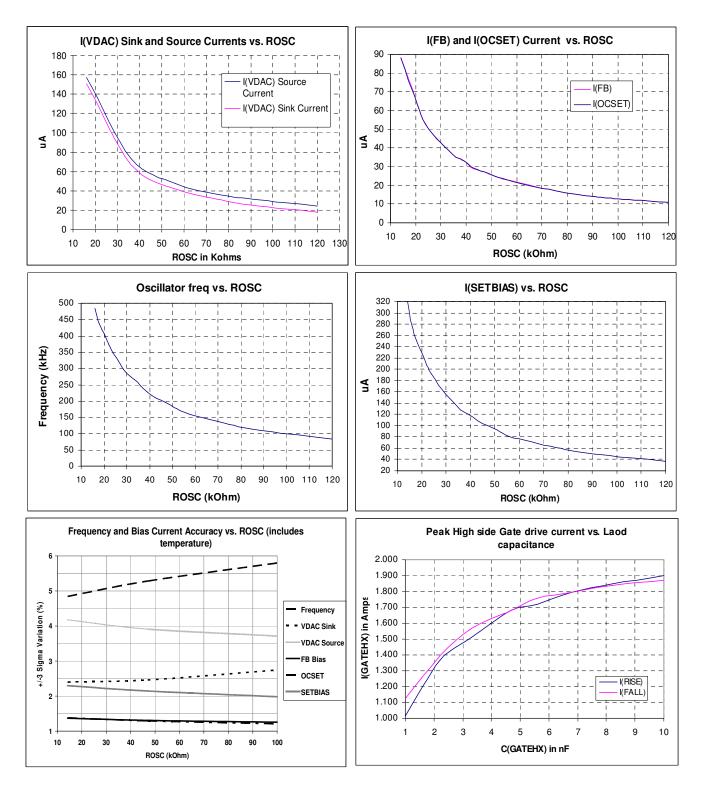
| PARAMETER                                     | TEST CONDITION   | MIN  | TYP  | MAX  | UNIT          |
|---|--|------|------|------|---------------|
| Share Adjust Error Amplifier                  |  |      |      |      |               |
| Input Offset Voltage                          | Note 1   | -5   | 0    | 5    | mV            |
| MAX Duty Cycle Adjust Ratio                   | Compare Duty Cycle to GATEHX   | 1.5  | 2.0  |      |               |
| MIN Duty Cycle Adjust Ratio                   | Compare Duty Cycle to GATEHX   | 0.6  | 0.5  |      |               |
| Transconductance                              | Note 1   | 100  | 200  | 300  | μ <b>A</b> /V |
| SCOMPX Source/Sink Current                    |  | 16   | 22   | 28   | μA            |
| Equal Duty Cycle Comparator<br>Threshold      |  | 0.45 | 0.60 | 0.95 | V             |
| Duty Cycle Match at Startup                   | Compare Duty Cycle to GATEHX   | -5   | -1   | 5    | %             |
| SCOMPX Precharge Current                      | V(SS/DEL)=0  | 300  | 450  | 700  | μA            |
| 0% Duty Cycle Comparator                      |  |      |      |      |               |
| Threshold Voltage                             | Below Internal Ramp1 Start Voltage   | 80   | 130  | 180  | mV            |
| Propagation Delay                             | VCCLX= 8V. Step EAOUT from .8V to<br>.3V and measure time to GATELX<br>transition to < 7V.           |      | 200  | 400  | ns            |
| Body Breaking Disable<br>Comparator Threshold | Compare V(FB) to V(VDAC)   | 50   | 75   | 110  | mV            |
| OVP   |  |      |      |      |               |
| VR10.X Comparator Threshold                   | VID_SEL=0V. Compare to V(VDAC)   | 120  | 150  | 200  | mV            |
| AMD Comparator Threshold                      | Float VID_SEL. Compare to V(VDAC)  | 360  | 450  | 600  | mV            |
| Power-up Headroom for OVP<br>Flag             | VCC=OVPSNS where V(OVP)>0.5V.<br>Same for 5VUVL=OVPSNS.  | 0.8  | 1.1  | 1.8  | V             |
| OVPSNS Threshold at Power-<br>up              | VCC=2V, V(OVP) >0.5V. Same for V(5VUVL)=2V.  | 0.3  | 0.48 | 0.85 | V             |
| SS/DEL Power-up Clear<br>Threshold            | VCC=12V, V(OVPSNS)=1V,<br>VDAC=1.6V, where OVP<0.5V  | 0.35 | 0.60 | 0.95 | V             |
| Propagation Delay                             | VCCLX= 8V. V(EAOUT)=0V. Step<br>OVPSNS 540mV + V(VDAC). Measure<br>time to GATELX transition to >1V. |      | 275  | 400  | ns            |
| OVP Source Current                            | V(OVP)=0.5V, VCC=1.8V, 5VUVL=0V  | 10   | 75   |      | μA            |
| OVP Pull Down Resistance                      | OVP to LGND  | 30   | 60   | 100  | kΩ            |
| OVP High Voltage                              | I(OVP)=10uA, V(VCC) or V(5VUVL)-<br>V(OVP), VCC=1.8V   | 0.4  | 0.70 | 1.1  | V             |
| OVPSNS Bias Current                           |  | -1   | 0.3  | 1.5  | uA            |
| 5VREF   |  |      |      |      |               |
| Short Circuit Current                         |  | 20   | 45   | 60   | mA            |
| Supply Voltage                                | I(5VREF)=0A  | 4.5  | 5    | 5.5  | V             |
| General                                       |  |      |      |      |               |
| VCC Supply Current                            | V(VCC)=21V   | 33   | 38   | 44   | mA            |
| VOSNS- Current                                | -0.3V ≤ VOSNS- ≤ 0.3V, All VID Codes   | 3.2  | 3.7  | 4.2  | mA            |
| VCCHX and VCCL3 Current                       | V(VCCHX)=28V, V(VCCL3)=14V   | 3    | 5    | 7    | mA            |
| VCCL1_2 Supply Current                        | V(VCCL1_2)=14V   | 6    | 10   | 17   | mA            |
| 5VUVL Supply Current                          | V(5VUVL)=5V, no OVP condition  | 100  | 200  | 400  | uA            |

**Note 1:** Guaranteed by design, but not tested in production

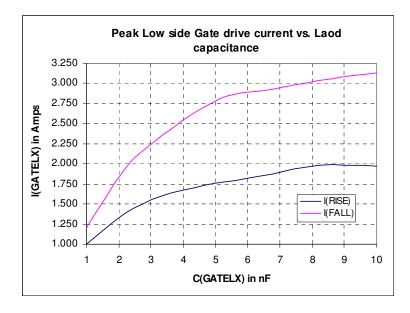
Note 2: Critical limits are identified with **bold** text

Note 3: VDAC Output is trimmed to compensate for Error Amp input offsets errors

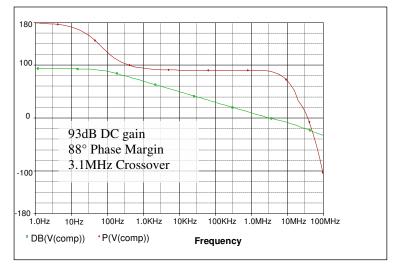
# **TYPICAL OPERATING CHARACTERISTICS**



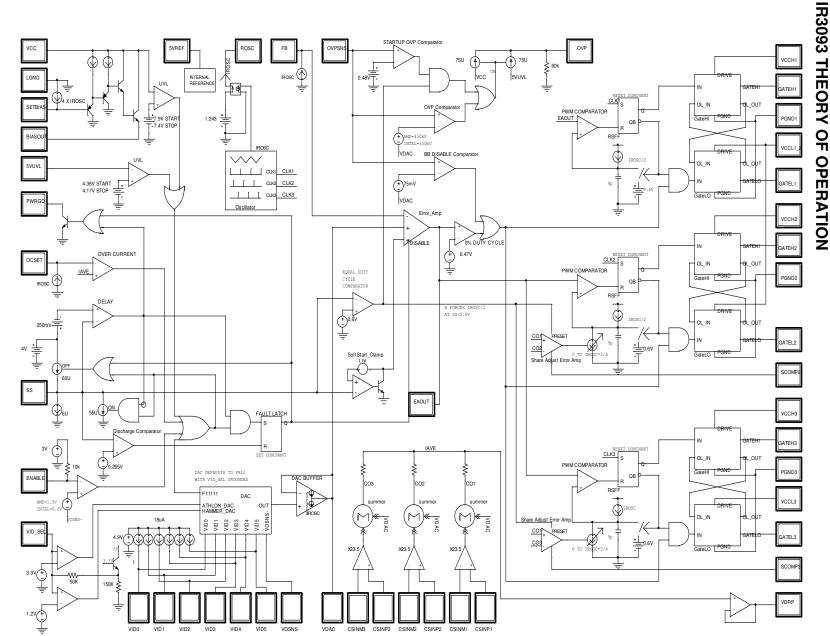
# International **IOR** Rectifier



#### Error Amplifier Frequency Response



# Figure 1 – IR3093 Block Diagram



IR3093PbF

International **IOR** Rectifier

#### **PWM Operation**

The IR3093 is a fully integrated 3 phase interleaved PWM control IC which uses voltage mode control with trailing edge modulation. A high-gain wide-bandwidth voltage type Error Amplifier in the Control IC is used for the voltage control loop. The PWM block diagram is shown in Figure 2.

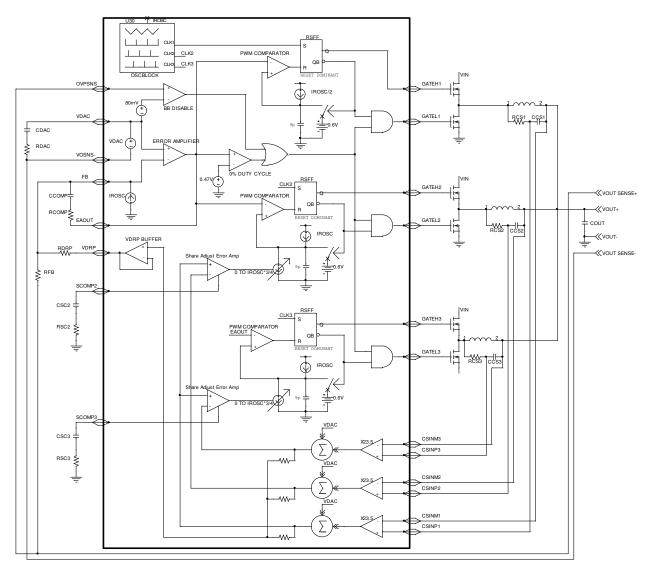


Figure 2 – PWM Block Diagram

Refer to Figure 3. Upon receiving a clock pulse, the RSFF is set, the internal PWM ramp voltage begins to increase, the low side driver is turned off, and the high side driver is then turned on. For phase 1, an internal 9pf capacitor is charged by a current source that proportional to the switching frequency resulting in a ramp rate of 50mV per percent duty cycle. For example, if the steady-state operating switch node duty cycle is 10%, then the internal ramp amplitude is typically 500mV from the starting point (or floor) to the crossing of the EAOUT control voltage. When the PWM ramp voltage exceeds the Error Amplifier's output voltage, the RSFF is reset. This turns off the high side driver, turns on the low side driver, and discharges the PWM ramp to 0.6V until the next clock pulse.

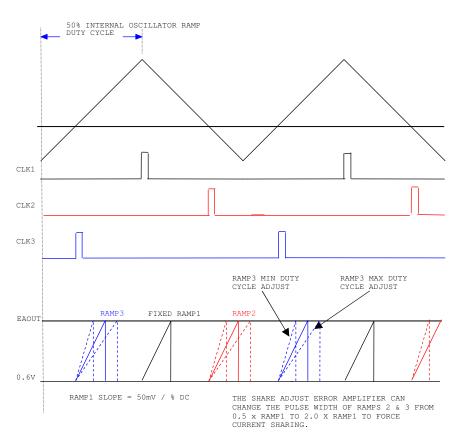


Figure 3 – 3 Phase Oscillator and PWM Waveforms

The RSFF is reset dominant allowing both phases to go to zero duty cycle within a few tens of nanoseconds in response to a load step decrease. Phases can overlap and go to 100% duty cycle in response to a load step increase with turn-on gated by the clock pulses. An Error Amplifier output voltage greater than the common mode input range of the PWM comparator results in 100% duty cycle regardless of the voltage of the PWM ramp. This arrangement guarantees the Error Amplifier is always in control and can demand 0 to 100% duty cycle as required. It also favors response to a load step decrease which is appropriate given the low output to input voltage ratio of most systems. The inductor current will increase much more rapidly than decrease in response to load transients.

This control method is designed to provide "single cycle transient response" where the inductor current changes in response to load transients within a single switching cycle maximizing the effectiveness of the power train and minimizing the output capacitor requirements.

## Body Braking<sup>™</sup>

In a conventional synchronous buck converter, the minimum time required to reduce the current in the inductor in response to a load step decrease is;

$$T_{SLEW} = [L \times (I_{MAX} - I_{MIN})] / Vout$$

The slew rate of the inductor current can be significantly increased by turning off the synchronous rectifier in response to a load step decrease. The switch node voltage is then forced to decrease until conduction of the synchronous rectifier's body diode occurs. This increases the voltage across the inductor from Vout to Vout +  $V_{BODY \ DIODE}$ . The minimum time required to reduce the current in the inductor in response to a load transient decrease is now;

$$T_{SLEW} = [L \times (I_{MAX} - I_{MIN})] / (Vout + V_{BODY DIODE})$$

# International **TOR** Rectifier

Since the voltage drop in the body diode is often higher than output voltage, the inductor current slew rate can be increased by 2X or more. This patent pending technique is referred to as "body braking" and is accomplished through the "0% Duty Cycle Comparator". If the Error Amplifier's output voltage drops below 0.47V, this comparator turns off the low side gate driver.

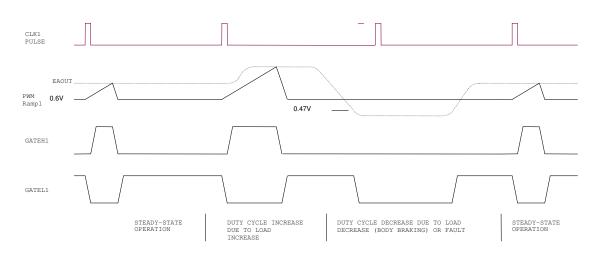


Figure 4 depicts PWM operating waveforms under various conditions

Figure 4 – PWM Operating Waveforms

#### **Current Sense Amplifier**

A high speed differential current sense amplifier is shown in Figure 5. Its gain decreases with increasing temperature and is nominally 23.5 at 25°C and 20.4 at 125°C (-1400 ppm/°C). This reduction of gain tends to compensate the 3850 ppm/°C increase in inductor DCR. Since in most designs the IR3093 IC junction is hotter than the inductors these two effects tend to cancel such that no additional temperature compensation of the load line is required.

The current sense amplifier can accept positive differential input up to 75mV and negative up to -25mV before clipping. The output of the current sense amplifier is summed with the DAC voltage which is used for over current protection, voltage positioning and current sharing.

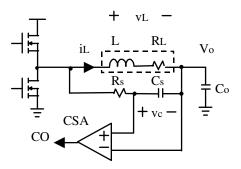


Figure 5 – Inductor Current Sensing and Current Sense Amplifier

#### VCC Under Voltage Lockout (UVLO)

The VCC UVLO function monitors the IR3093's VCC supply pin and ensures enough voltage is available to power the internal circuitry. During power-up the fault latch is reset when VCC exceeds 7.9V and all other faults are cleared. The fault latch is set when VCC drops below 7.4V and SS/DEL is below 3.75V.

#### 5VUVL Under Voltage Lockout (5VUVL)

The 5VUVL function is provided for converters using a separate voltage supply other than VCC for gate driver bias. The 5VUVL comparator prevents operation by discharging SS/DEL below 3.75V to force EAOUT low. The 5VUVL comparator has an OK threshold of 4.36V ensuring adequate gate drive voltage is present and a fault threshold of 4.17V.

#### Power Good Output

The PWRGD pin is an open-collector output and should be pulled up to a voltage source through a resistor. During soft start, the PWRGD remains low until the output voltage is in regulation and SS/DEL is above 3.75V. The PWRGD pin becomes low if the fault latch is set. A high level at the PWRGD pin indicates that the converter is in operation and has no fault, but does not ensure the output voltage is within the specification. Output voltage regulation within the design limits can logically be assured however, assuming no component failure in the system.

#### Tri-State Gate Drivers

The GATELX drivers can pull down up to 3.5A peak current and source up to 1.5A. The GATEHX drivers can source and sink up to 1.5A peak current. An adaptive non-overlap circuit monitors the voltage on the GATEHX and GATELX pins to prevent MOSFET shoot-through current while minimizing body diode conduction.

The Error Amplifier output of the Control IC drives low in response to any fault condition such as VCC input under voltage or output overload. The 0% duty cycle comparator detects this and drives both gate outputs low. This tri-state operation prevents negative inductor current and negative output voltage during power-down.

The Gate Drivers revert to a high impedance "off" state at VCCLX and VCCHX supply voltages below the normal operating range. An  $80k\Omega$  resistor is connected across the GATEX and PGNDX pins to prevent the GATEX voltage from rising due to leakage or other cause under these conditions.

#### Over Voltage Protection (OVP)

The output Over-Voltage Protection comparator monitors the output voltage through the OVPSNS pin, the positive remote sense point. If OVPSNS exceeds VDAC plus 150mV (for VR-10.0, 450mV for OPTERON and ATHLON, selected with the VID\_SEL pin), both GATEL pins drive high and the OVP pin sources 75uA current. The OVP circuit over-rides the normal PWM operation and will fully turn-on the low side MOSFET within approximately 150ns. The low side MOSFET will remain ON until the over-voltage condition ceases. The lower MOSFETs alone can not clamp the output voltage however an SCR or N-MOSFET could be triggered with the OVP pin to prevent processor damage.

In the event of a high side MOSFET short, the OVP flag is activated with as little supply voltage as possible. The OVPSNS pin is compared against both VCC and 5VUVL for OVP conditions at power-up. VCC is monitored for conversion off 12V, 5VUVL is monitored for conversion off 5V. The OVP pin flags a voltage greater than 0.5V with supply voltages as low as 1.0V. This headroom voltage varies inversely with temperature. An external comparator can be used to disable the silver box, activate a crowbar, or supply source.

The overall system must be considered when designing for OVP. In many cases the over-current protection of the AC-DC or DC-DC converter supplying the multiphase converter will be triggered thus providing effective protection without damage as long as all PCB traces and components are sized to handle the worst-case maximum current. If this is not possible, a fuse can be added in the input supply to the multiphase converter. A Body Braking<sup>TM</sup> Disable Comparator has been included to prevent false OVP firing during dynamic VID down changes. The BB DISABLE Comparator disables Body Braking<sup>TM</sup> when FB exceeds VDAC by 75mV. The low side MOSFETs will then be controlled to keep V(FB) and V(VOUT) within 80mV of V(VDAC), below the 150mV INTEL OVP trip point.

IR3093PbF

# **APPLICATIONS INFORMATION**

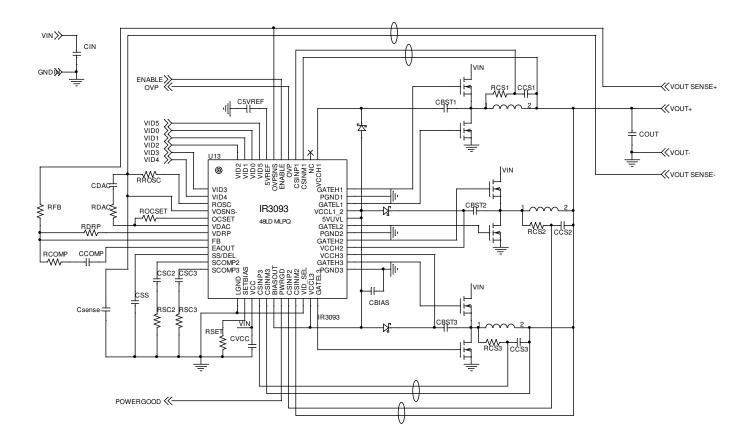


Figure 6 – System Diagram

#### VID Control

The IR3093 provides three different microprocessor solutions. The VID\_SEL pin selects the appropriate Digital-to-Analog Converters (DAC), VID threshold voltages, and Over Voltage Protection (OVP) threshold for either VR-10.0, OPTERON, or ATHLON solutions. Reference voltages are shown in Table 1. The DAC output voltage is available at the VDAC pin. A detailed block diagram of the VID control circuitry can be found in Figure 7. The VID pins are internally pulled up to 4.9V by 18uA current sources. The VID input comparators have a 0.6V threshold for VR-10.0 or 1.65V threshold for OPTERON and ATHLON. The selected DAC voltage is provided at the Error Amplifier positive input and to the VDAC pin by the trans-conductance DAC Buffer.

The VDAC voltage is trimmed to the Error Amplifier output voltage with EAOUT tied to FB via an accurate resistor. This compensates DAC Buffer input offset, Error Amplifier input offset, and errors in the generation of the FB bias current which is based on  $R_{ROSC}$ . This trim method provides a 0.5% system accuracy.

The IR3093 can accept changes in the VID code while operating and vary the VDAC voltage accordingly. The IR3093 detects a VID change and blanks the DAC output response for 400ns to verify the new code is valid and not due to skew or noise. The sink/source capability of the VDAC buffer amp is programmed by the same external resistor that sets the oscillator frequency, R<sub>ROSC</sub>. The slew rate of the voltage at the VDAC pin can be adjusted by an external capacitor between VDAC pin and the VOSNS- pin. A resistor connected in series with this capacitor is

# International **TOR** Rectifier

required to compensate the VDAC buffer amplifier. Digital VID transitions result in a smooth analog transition of the VDAC voltage and converter output voltage minimizing inrush currents in the input and output capacitors and overshoot of the output voltage.

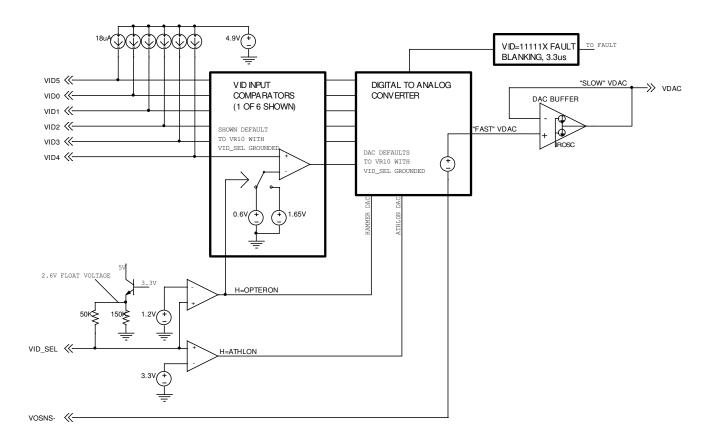


Figure 7– VID Control Block Diagram

### VID = 11111X Fault

VID codes of 111111 and 111110 will set the fault latch and disable the Error Amplifier once SS/DEL is below 3.75V.

| AMD Opteron VID Table |   |                             |         |        |                  | AMD ATHLON VID Table   |  |      |      |      |      |                  |  |  |
|-----------------------|---|-----------------------------|---------|--------|------------------|--|--|------|------|------|------|------------------|--|--|
| positi                | oned 5  | en. V(V<br>0mV hig<br>below | gher th | an Vou |                  | VIDSEL to VCC. V(VDAC) is pre-<br>positioned 50mV higher than Vout value<br>listed below for load positioning. |  |      |      |      |      |                  |  |  |
| ROSC                  | Vout is measured at EAOUT with<br>ROSC=47K and a 1890 ohm resistor<br>connecting FB to EAOUT to cancel the<br>50mV pre-position offset. |                             |         |        |                  |  | Vout is measured at EAOUT with<br>ROSC=47K and a 1890 ohm resistor<br>connecting FB to EAOUT to cancel th<br>50mV pre-position offset. |      |      |      |      |                  |  |  |
| VID4                  | VID3  | VID2                        | VID1    | VID0   | Vout<br>(V)      |  | VID4   | VID3 | VID2 | VID1 | VID0 | Vout<br>(V)      |  |  |
| 0                     | 0   | 0                           | 0       | 0      | 1.550            |  | 0  | 0    | 0    | 0    | 0    | 1.850            |  |  |
| 0                     | 0   | 0                           | 0       | 1      | 1.525            |  | 0  | 0    | 0    | 0    | 1    | 1.825            |  |  |
| 0                     | 0   | 0                           | 1       | 0      | 1.500            |  | 0  | 0    | 0    | 1    | 0    | 1.800            |  |  |
| 0                     | 0   | 0                           | 1       | 1      | 1.475            |  | 0  | 0    | 0    | 1    | 1    | 1.775            |  |  |
| 0                     | 0   | 1                           | 0       | 0      | 1.450            |  | 0  | 0    | 1    | 0    | 0    | 1.750            |  |  |
| 0                     | 0   | 1                           | 0       | 1      | 1.425            |  | 0  | 0    | 1    | 0    | 1    | 1.725            |  |  |
| 0                     | 0   | 1                           | 1       | 0      | 1.400            |  | 0  | 0    | 1    | 1    | 0    | 1.700            |  |  |
| 0                     | 0   | 1                           | 1       | 1      | 1.375            |  | 0  | 0    | 1    | 1    | 1    | 1.675            |  |  |
| 0                     | 1   | 0                           | 0       | 0      | 1.350            |  | 0  | 1    | 0    | 0    | 0    | 1.650            |  |  |
| 0                     | 1   | 0                           | 0       | 1      | 1.325            |  | 0  | 1    | 0    | 0    | 1    | 1.625            |  |  |
| 0                     | 1   | 0                           | 1       | 0      | 1.300            |  | 0  | 1    | 0    | 1    | 0    | 1.600            |  |  |
| 0                     | 1   | 0                           | 1       | 1      | 1.275            |  | 0  | 1    | 0    | 1    | 1    | 1.575            |  |  |
| 0                     | 1   | 1                           | 0       | 0      | 1.250            |  | 0  | 1    | 1    | 0    | 0    | 1.550            |  |  |
| 0                     | 1   | 1                           | 0       | 1      | 1.225            |  | 0  | 1    | 1    | 0    | 1    | 1.525            |  |  |
| 0                     | 1   | 1                           | 1       | 0      | 1.200            |  | 0  | 1    | 1    | 1    | 0    | 1.500            |  |  |
| 0                     | 1   | 1                           | 1       | 1      | 1.175            |  | 0  | 1    | 1    | 1    | 1    | 1.475            |  |  |
| 1                     | 0   | 0                           | 0       | 0      | 1.150            |  | 1  | 0    | 0    | 0    | 0    | 1.450            |  |  |
| 1                     | 0   | 0                           | 0       | 1      | 1.125            |  | 1  | 0    | 0    | 0    | 1    | 1.425            |  |  |
| 1                     | 0   | 0                           | 1       | 0      | 1.100            |  | 1  | 0    | 0    | 1    | 0    | 1.400            |  |  |
| 1                     | 0   | 0                           | 1       | 1      | 1.075            |  | 1  | 0    | 0    | 1    | 1    | 1.375            |  |  |
| 1                     | 0   | 1                           | 0       | 0      | 1.050            |  | 1  | 0    | 1    | 0    | 0    | 1.350            |  |  |
| 1                     | 0   | 1                           | 0       | 1      | 1.025            |  | 1  | 0    | 1    | 0    | 1    | 1.325            |  |  |
| 1                     | 0   | 1                           | 1       | 0      | 1.000            |  | 1  | 0    | 1    | 1    | 0    | 1.300            |  |  |
| 1                     | 0   | 1                           | 1       | 1      | 0.975            |  | 1  | 0    | 1    | 1    | 1    | 1.275            |  |  |
| 1                     | 1   | 0                           | 0       | 0      | 0.950            |  | 1  | 1    | 0    | 0    | 0    | 1.250            |  |  |
| 1                     | 1   | 0                           | 0       | 1      | 0.925            |  | 1  | 1    | 0    | 0    | 1    | 1.225            |  |  |
| 1                     | 1   | 0                           | 1       | 0      | 0.900            |  | 1  | 1    | 0    | 1    | 0    | 1.200            |  |  |
| 1                     | 1   | 0                           | 1       | 1      | 0.875            |  | 1  | 1    | 0    | 1    | 1    | 1.175            |  |  |
| 1                     | 1   | 1                           | 0       | 0      | 0.850            |  | 1  | 1    | 1    | 0    | 0    | 1.150            |  |  |
| 1                     | 1   | 1                           | 0       | 1      | 0.825            |  | 1  | 1    | 1    | 0    | 1    | 1.125            |  |  |
| 1                     | 1   | 1                           | 1       | 0      | 0.800            |  | 1  | 1    | 1    | 1    | 0    | 1.100            |  |  |
| 1                     | 1   | 1                           | 1       | 1      | OFF <sup>4</sup> |  | 1  | 1    | 1    | 1    | 1    | OFF <sup>4</sup> |  |  |

Note: 4 Output disabled (Fault mode)

# Table 1 - Voltage Identification (VID)

| INTEL VR-10.0 VID Table (VID_SEL Grounded, measured at EAOUT=FB.) |         |        |         |                  |      |                  |  |      | ]       |        |         |           |      |        |
|---|---------|--------|---------|------------------|------|------------------|--|------|---------|--------|---------|-----------|------|--------|
| Pro   | ocessor | Pins ( | 0 = low | , 1 = hi <u></u> | gh)  | Vout             |  | Pro  | ocessor | Pins ( | 0 = low | , 1 = hig | gh)  | Vout   |
| VID4  | VID3    | VID2   | VID1    | VID0             | VID5 | (V)              |  | VID4 | VID3    | VID2   | VID1    | VID0      | VID5 | (V)    |
| 0   | 1       | 0      | 1       | 0                | 0    | 0.8375           |  | 1    | 1       | 0      | 1       | 0         | 0    | 1.2125 |
| 0   | 1       | 0      | 0       | 1                | 1    | 0.8500           |  | 1    | 1       | 0      | 0       | 1         | 1    | 1.2250 |
| 0   | 1       | 0      | 0       | 1                | 0    | 0.8625           |  | 1    | 1       | 0      | 0       | 1         | 0    | 1.2375 |
| 0   | 1       | 0      | 0       | 0                | 1    | 0.8750           |  | 1    | 1       | 0      | 0       | 0         | 1    | 1.2500 |
| 0   | 1       | 0      | 0       | 0                | 0    | 0.8875           |  | 1    | 1       | 0      | 0       | 0         | 0    | 1.2625 |
| 0   | 0       | 1      | 1       | 1                | 1    | 0.9000           |  | 1    | 0       | 1      | 1       | 1         | 1    | 1.2750 |
| 0   | 0       | 1      | 1       | 1                | 0    | 0.9125           |  | 1    | 0       | 1      | 1       | 1         | 0    | 1.2875 |
| 0   | 0       | 1      | 1       | 0                | 1    | 0.9250           |  | 1    | 0       | 1      | 1       | 0         | 1    | 1.3000 |
| 0   | 0       | 1      | 1       | 0                | 0    | 0.9375           |  | 1    | 0       | 1      | 1       | 0         | 0    | 1.3125 |
| 0   | 0       | 1      | 0       | 1                | 1    | 0.9500           |  | 1    | 0       | 1      | 0       | 1         | 1    | 1.3250 |
| 0   | 0       | 1      | 0       | 1                | 0    | 0.9625           |  | 1    | 0       | 1      | 0       | 1         | 0    | 1.3375 |
| 0   | 0       | 1      | 0       | 0                | 1    | 0.9750           |  | 1    | 0       | 1      | 0       | 0         | 1    | 1.3500 |
| 0   | 0       | 1      | 0       | 0                | 0    | 0.9875           |  | 1    | 0       | 1      | 0       | 0         | 0    | 1.3625 |
| 0   | 0       | 0      | 1       | 1                | 1    | 1.0000           |  | 1    | 0       | 0      | 1       | 1         | 1    | 1.3750 |
| 0   | 0       | 0      | 1       | 1                | 0    | 1.0125           |  | 1    | 0       | 0      | 1       | 1         | 0    | 1.3875 |
| 0   | 0       | 0      | 1       | 0                | 1    | 1.0250           |  | 1    | 0       | 0      | 1       | 0         | 1    | 1.4000 |
| 0   | 0       | 0      | 1       | 0                | 0    | 1.0375           |  | 1    | 0       | 0      | 1       | 0         | 0    | 1.4125 |
| 0   | 0       | 0      | 0       | 1                | 1    | 1.0500           |  | 1    | 0       | 0      | 0       | 1         | 1    | 1.4250 |
| 0   | 0       | 0      | 0       | 1                | 0    | 1.0625           |  | 1    | 0       | 0      | 0       | 1         | 0    | 1.4375 |
| 0   | 0       | 0      | 0       | 0                | 1    | 1.0750           |  | 1    | 0       | 0      | 0       | 0         | 1    | 1.4500 |
| 0   | 0       | 0      | 0       | 0                | 0    | 1.0875           |  | 1    | 0       | 0      | 0       | 0         | 0    | 1.4625 |
| 1   | 1       | 1      | 1       | 1                | 1    | OFF <sup>4</sup> |  | 0    | 1       | 1      | 1       | 1         | 1    | 1.4750 |
| 1   | 1       | 1      | 1       | 1                | 0    | OFF <sup>4</sup> |  | 0    | 1       | 1      | 1       | 1         | 0    | 1.4875 |
| 1   | 1       | 1      | 1       | 0                | 1    | 1.1000           |  | 0    | 1       | 1      | 1       | 0         | 1    | 1.5000 |
| 1   | 1       | 1      | 1       | 0                | 0    | 1.1125           |  | 0    | 1       | 1      | 1       | 0         | 0    | 1.5125 |
| 1   | 1       | 1      | 0       | 1                | 1    | 1.1250           |  | 0    | 1       | 1      | 0       | 1         | 1    | 1.5250 |
| 1   | 1       | 1      | 0       | 1                | 0    | 1.1375           |  | 0    | 1       | 1      | 0       | 1         | 0    | 1.5375 |
| 1   | 1       | 1      | 0       | 0                | 1    | 1.1500           |  | 0    | 1       | 1      | 0       | 0         | 1    | 1.5500 |
| 1   | 1       | 1      | 0       | 0                | 0    | 1.1625           |  | 0    | 1       | 1      | 0       | 0         | 0    | 1.5625 |
| 1   | 1       | 0      | 1       | 1                | 1    | 1.1750           |  | 0    | 1       | 0      | 1       | 1         | 1    | 1.5750 |
| 1   | 1       | 0      | 1       | 1                | 0    | 1.1875           |  | 0    | 1       | 0      | 1       | 1         | 0    | 1.5875 |
| 1   | 1       | 0      | 1       | 0                | 1    | 1.2000           |  | 0    | 1       | 0      | 1       | 0         | 1    | 1.6000 |

## INTEL VB-10.0 VID Table (VID SEL Grounded measured at EAOUT-EB.)

Note: 4. Output disabled (Fault mode)

#### Table 1 Continued - Voltage Identification (VID)

#### Slew Rate Programming Capacitor CDAC and Resistor RDAC

VDAC sink current ISINK and source current ISOURCE are determined by RROSC, and their value can be found using the curve in this data sheet. The slew rate of VDAC down-slope SRDOWN can be programmed by the external capacitor CDAC as defined in Equation (1) and shown in Figure 1. Resistor RDAC is used to compensate VDAC circuit and is determined by Equation (2). The slew rate of VDAC up-slope SRUP is proportional to the down-slope slew rate SRDOWN and is given by Equation (3).

$$C_{DAC} = \frac{I_{SINK}}{SR_{DOWN}} \tag{1}$$

$$R_{DAC} = 0.5 + \frac{3.2 * 10^{-15}}{C_{DAC}^{2}}$$
(2)  
$$SR_{UP} = \frac{I_{SOURCE}}{C_{DAC}}$$
(3)

$$T_{P} = \frac{C_{DAC}}{C_{DAC}}$$

#### Oscillator Resistor R<sub>ROSC</sub>

The oscillator frequency is programmable from 100kHz to 540kHz with an external resistor  $R_{ROSC}$  as shown in Figure 6 oscillator generates an internal 50% duty cycle sawtooth signal (Figure 3.) that is used to generate 120° out-of-phase timing pulses to set Phase 1,2 and 3 RS flip-flops. Once the switching frequency is chosen,  $R_{ROSC}$  can be determined from the curve in the Typical Operating Characteristics Section.

#### Soft Start, Over-Current Fault Delay, and Hiccup Mode

The IR3093 has a programmable soft-start function to limit the surge current during converter power-up. A capacitor connected between the SS/DEL and LGND pins controls soft start timing as well as over-current protection delay and hiccup mode timing.

Figure 8 depicts the various operating modes of the SS/DEL function. Under a no fault condition, the SS/DEL capacitor will charge. The SS/DEL charge soft-start duration is controlled by a 60uA charge current which charges CSS up to 4.0V. The Error Amplifier output is clamped low until SS/DEL reaches 1.1V. The Error Amplifier will then regulate the converter's output voltage to match the SS/DEL voltage less the 1.1V offset until it reaches the level determined by the VID inputs. The PWRGD signal is asserted once the SS/DEL voltage exceeds 3.75V.

Five different faults will immediately cause SS/DEL to begin discharging and set the Fault Latch once SS/DEL is below 3.75V;

- 1. VCC Under Voltage Lock Out
- 2. 5VUVL Under Voltage Lock Out
- 3. VID=11111x fault
- 4. Low Enable pin
- 5. Over Current Condition.

A delay is included if any fault condition occurs after a successful soft start sequence. This is required since momentary faults can occur as part of normal operation due to load transients such as exciting an over-current condition or a VID=11111x code while going through VID transitions. If any fault occurs during normal operation, the SS/DEL capacitor will discharge through a 55uA current sink but will not set the fault latch immediately. If the fault condition persists long enough for the SS/DEL capacitor to discharge below the 3.75V threshold of the delay comparator, the Fault latch will be set pulling the Error Amplifier's output low, inhibiting switching and de-asserting the PWRGD signal. The SS/DEL capacitor is then discharged through a 6uA discharge current resulting in a long hiccup duration.

The SS/DEL capacitor will continue to discharge until it reaches 0.265V where the fault latch is reset allowing a normal soft start to occur. If a fault condition is again encountered during the soft start cycle, the fault latch will be set without any delay and hiccup mode will begin. During hiccup mode the 10 to 1 charge to discharge ratio results in a 9.1% hiccup mode duty cycle regardless of at what point a fault condition occurs.

The converter can be disabled if the SS/DEL pin is pulled below 0.9V.

# International **tor** Rectifier

# IR3093PbF

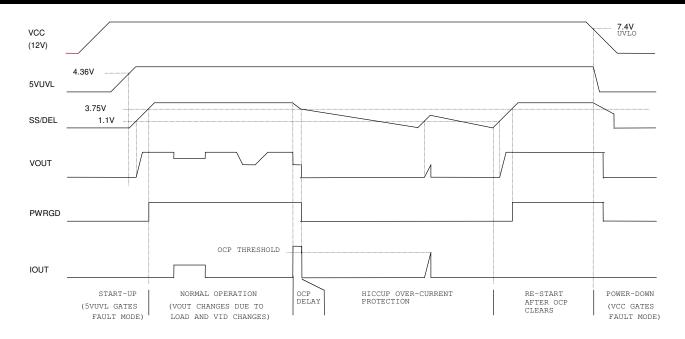


Figure 8 – Operating Waveforms

Soft-start delay time tSSDEL is the time SS/DEL charged up to 1.1V. After that the error amplifier output is released to allow the soft start. The soft start time tss represents the time during which converter output voltage rises from zero to Vo. tss can be programmed by Css using equation (4).

$$C_{SS} = \frac{I_{CHG} * t_{SS}}{V_O} = \frac{60 * 10^{-6} * t_{SS}}{V_O}$$
(4)

Once CSS is chosen, the soft start delay time tSSDEL, the over-current fault latch delay time tOCDEL, and the delay time tVccPG from output voltage (VO) in regulation to Power Good are fixed and shown in equation (5), (6) and (7) respectively.

$$t_{SSDEL} = \frac{C_{SS} * \Delta V}{I_{CHG}} = \frac{C_{SS} * 1.1}{60 * 10^{-6}}$$
(5)

$$t_{OCDEL} = \frac{C_{SS} * \Delta V}{I_{DISCHG}} = \frac{C_{SS} * 0.25}{61 * 10^{-6}}$$
(6)

$$t_{VccPG} = \frac{C_{SS} * \Delta V}{I_{CHG}} = \frac{C_{SS} * (3.75 - V_o - 1.1)}{60 * 10^{-6}}$$
(7)

#### **Over Current Protection (OCP)**

The current limit threshold is set by a resistor connected between the OCSET and VDAC pins. If the average Current Sense Amplifier output plus VDAC voltage exceeds the OCSET voltage, the over-current protection is triggered.

# International **TOR** Rectifier

A delay is included if an over-current condition occurs after a successful soft-start sequence. This is required since over-current conditions can occur as part of normal operation due to load transients or VID transitions. If an over-current fault occurs during normal operation, the Over Current Comparator will initiate the discharge of the capacitor at SS/DEL but will not set the fault latch immediately. If the over-current condition persists long enough for the SS/DEL capacitor to discharge below the 250mV offset of the delay comparator, the Fault latch will be set pulling the Error Amplifier's output low inhibiting switching in the phase ICs and de-asserting the PWRGD signal. See Soft Start, Over-Current Fault Delay, and Hiccup Mode. The hiccup mode duty cycle of over current protection is determined by the ratio of the charge to discharge current and is fixed at 9.1% for the ratio of 10 to 1.

The inductor DC resistance RL is utilized to sense the inductor current. The current limit threshold is set by a resistor ROCSET connected between the OCSET and VDAC pins, as shown in Fig1. ILIMIT is the required over current limit. IOCSET, the bias current of OCSET pin, is set by  $R_{ROSC}$  and is determined by the curve in this data sheet. OCP need to satisfy the high temperature condition. RL\_MAX and RL\_ROOM are the inductor DCR at maximum temperature TL\_MAX and room temperature T\_ROOM respectively, the maximum inductor DCR can be calculated from Equation (8)

$$R_{L_{MAX}} = R_{L_{ROOM}} * [1 + 3850 * 10^{-6} * (T_{L_{MAX}} - T_{ROOM})]$$
(8)

The current sense amplifier gain of IR3093 decreases with temperature at the rate of1400 PPM, which compensates part of the inductor DCR increase. The minimum current sense amplifier gain at the maximum IC temperature TIC\_MAX is calculated from Equation (9).

$$G_{CS\_MIN} = G_{CS\_ROOM} * [1 - 1400 * 10^{-6} * (T_{IC\_MAX} - T_{ROOM})]$$
(9)

ROCSET can be calculated by the following equation (10), where  $\Delta I$  is the ripple current in each output inductor.

$$R_{OCSET} = \left[\left(\frac{I_{LIMIT}}{3} + \frac{\Delta I}{2}\right) * R_{L_{MAX}}\right] * G_{CS_{MIN}} / I_{OCSET}$$
(10)

$$\Delta I = \frac{Vo*(Vin-Vo)}{L*Vin*fsw}$$
(11)

#### **Adaptive Voltage Positioning**

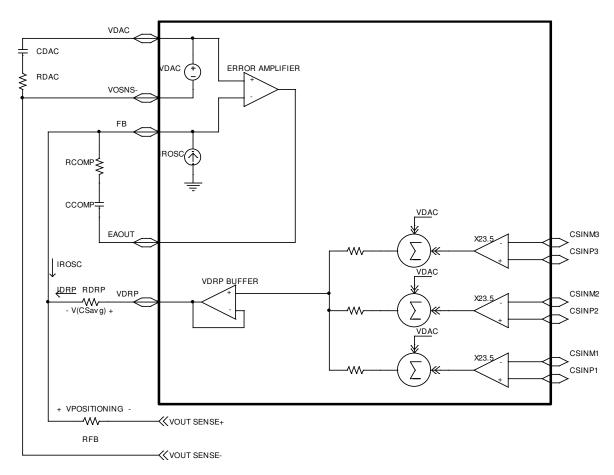
Adaptive voltage positioning is needed to reduce output voltage deviations during load transients and power dissipation of the load when it is drawing maximum current. The circuitry related to voltage positioning is shown in Figure 8. Resistor RFB is connected between the Error Amplifier's inverting input pin FB and the converter's output voltage. An internal current source whose value is programmed by the same external resistor that programs the oscillator frequency, R<sub>ROSC</sub>, pumps current out of the FB pin. The FB bias current develops a positioning voltage drop across RFB which forces the converter's output voltage lower to V(VDAC)-I(FB)\* RFB to maintain a balance at the Error Amplifier inputs. RFB is selected to program the desired amount of fixed offset voltage below the DAC voltage.

The voltage at the VDRP pin is an average of three phase Current Sense Amplifiers and represents the sum of the VDAC voltage and the average inductor current of all the phases. The VDRP pin is connected to the FB pin through the resistor. The Error Amplifier forces the voltage on the FB pin to equal VDAC through the power supply loop therefore the current through RDRP is equal to (VDRP-VDAC) / RDRP. As the load current increases, the VDRP voltage increases accordingly which results in an increase RFB current, further positioning the output regulated voltage lower thus making the output voltage reduction proportional to an increase in load current. The droop impedance or output impedance of the converter can thus be programmed by the resistor RDRP. The offset and slope of the converter output impedance are independent of the VDAC voltage.

# International **TOR** Rectifier

AMD specifies the acceptable power supply regulation window as ±50mV around their specified VID tables. VR-10.0 specifies the VID table voltages as the absolute maximum power supply voltage. In order to have all three DAC options, the OPTERON and ATHLON DAC output voltages are pre-positioned 50mV higher than listed in AMD specs. During testing, a series resistor is placed between EAOUT and FB to cancel the additional 50mV out of the DAC. The FB bias current, equal to IROSC, develops the 50mV cancellation voltage. Trimming the VDAC voltage by monitoring V(EAOUT) with this 50mV cancellation resistor in circuit also trims out errors in the FB bias current.

The VDRP pin voltage represents the average current of the converter plus the DAC voltage. The load current can be retrieved by subtracting the VDAC voltage from the VDRP voltage.



#### Figure 9 - Adaptive voltage positioning

A resistor RFB between FB pin and the converter output is used to create output voltage offset VO\_NLOFST which is the difference between VDAC voltage and output voltage at no load condition. An internal current source whose value is programmed by the same external resistor that programs the oscillator frequency, R<sub>ROSC</sub>, pumps current I<sub>FB</sub> out of the FB pin.

The VDRP pin is connected to the FB pin through the Adaptive Voltage Positioning Resistor RDRP. Adaptive voltage positioning lowers the converter voltage by RO\*IO, where RO is the required output impedance of the converter. RFB and RDRP are determined by (12) and (13) respectively, where RO is the required output impedance of the converter.

$$R_{FB} = \frac{V_{O_-NLOFST}}{I_{FB}}$$
(12)

$$R_{DRP} = \frac{R_{FB} * R_{L_{-}MAX} * G_{CS_{-}MIN}}{n * R_{O}}$$
(13)

#### Lossless Average Inductor Current Sensing

Inductor current can be sensed by connecting a series resistor and a capacitor network in parallel with the inductor and measuring the voltage across the capacitor. The equation of the sensing network is,

$$v_C(s) = v_L(s) \frac{1}{1 + sR_sC_s} = i_L(s) \frac{R_L + sL}{1 + sR_sC_s}$$

Usually the resistor Rcs and capacitor Ccs are chosen so that the time constant of Rcs and Ccs equals the time constant of the inductor which is the inductance L over the inductor DCR. If the two time constants match, the voltage across Ccs is proportional to the current through L, and the sense circuit can be treated as if only a sense resistor with the value of RL was used. The mismatch of the time constants does not affect the measurement of inductor DC current, but affects the AC component of the inductor current.

The advantage of sensing the inductor current versus high side or low side sensing is that actual output current being delivered to the load is obtained rather than peak or sampled information about the switch currents. The output voltage can be positioned to meet a load line based on real time information. Except for a sense resistor in series with the inductor, this is the only sense method that can support a single cycle transient response. Other methods provide no information during either load increase (low side sensing) or load decrease (high side sensing).

An additional problem associated with peak or valley current mode control for voltage positioning is that they suffer from peak-to-average errors. These errors will show in many ways but one example is the effect of frequency variation. If the frequency of a particular unit is 10% low, the peak to peak inductor current will be 10% larger and the output impedance of the converter will drop by about 10%. Variations in inductance, current sense amplifier bandwidth, PWM prop delay, any added slope compensation, input voltage, and output voltage are all additional sources of peak-to-average errors.

Measure the inductance L and the inductor DC resistance RL. Pre-select the capacitor CCs and calculate RCsX as follows.

$$R_{CSX} = \frac{L/R_L}{C_{CS}} \tag{14}$$

#### Inductor DCR Temperature Correction

If the Current Sense Amplifier temperature dependent gain is not adequate to compensate the inductor DCR TC, a negative temperature coefficient (NTC) thermistor can be added. The thermistor should be placed close to the inductor and connected in parallel with the feedback resistor, as shown in Figure 9. The resistor in series with the thermistor is used to reduce the nonlinearity of the thermistor.

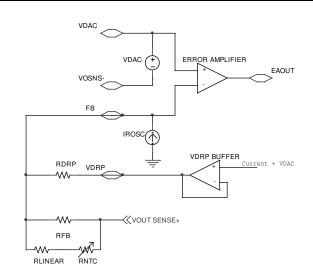


Figure 10 - Temperature compensation of inductor DCR

#### Remote Voltage Sensing

To compensate for impedance in the ground plane, the VOSNS- pin is used for remote sensing and connects directly to the load. The VDAC voltage is referenced to VOSNS- to avoid additional error terms or delay related to a separate differential amplifier. The capacitor connecting the VDAC and VOSNS- pins ensure that high speed transients are fed directly into the Error Amplifier without delay.

#### Master-Slave Current Share Loop

Current sharing between phases of the converter is achieved by a Master-Slave current share loop topology. The output of the Phase 1 Current Sense Amplifier sets the reference for the Share Adjust Error Amplifiers. Each Share Adjust Error Amplifier adjusts the duty cycle of its respective PWM Ramp and to force its input error to zero compared to the master Phase 1, resulting in accurate current sharing.

The maximum and minimum duty cycle adjust range of Ramps 2 & 3 compared to Ramp1 has been limited to a minimum of 0.5x and a maximum of 2.0x typical (see Figure 3.). The crossover frequency of the current share loop can be programmed with a capacitor at the SCOMPX pin so that the share loop does not interact with the output voltage loop.

The SCOMPX capacitor is driven by a trans-conductance stage capable of sourcing and sinking 22uA. The duty cycle of Ramps 2 & 3 inversely tracks the voltage on their SCOMPX pin; if V(SCOMP2) increases, Ramp2's slope will increase and the effective duty cycle will decrease resulting in a reduction in Phase 2's output current. Due to the limited 22uA source current, an SCOMPX pre-charge circuit has been included to pre-condition V(SCOMPX) so that the duty cycle of Ramps 2 & 3 are equal to Ramp1 prior to any GATEHX high pulses. The pre-condition circuit can source 450uA. The Equal Duty Cycle Comparator (see Block Diagram) activates a pre-charge circuit when SS/DEL is less than 0.6V. The Error Amplifier becomes active enabling GATEH switching when SS/DEL is above 1.1V.

#### Set BIASOUT voltage

BIASOUT pin provides 150mA open-looped regulated voltage for GATE drive bias, and the voltage is set by SETBIAS through an external resistor Rset connecting between SETBIAS pin and ground. Bias current  $I_{\text{SETBIAS}}$  is a function of ROSC. Rset is chosen by equation (15). VFD in the equation is the forward voltage drop across the Bootstrap diode.

$$R_{SET} = \frac{V_{BIASOUT} + V_{FD}}{I_{SETBIAS}}$$
(15)

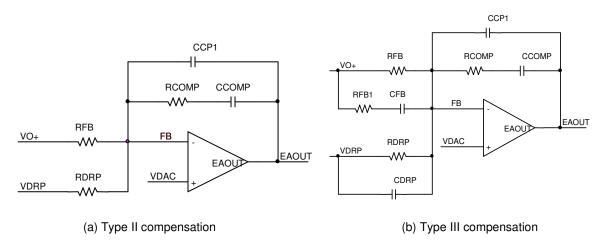
#### **Compensation of the Current Share Loop**

The crossover frequency of the current share loop should be at least one decade lower than that of the voltage loop in order to eliminate the interaction between the two loops. A 22nF capacitor from SCOMP to LGND is good for most of the applications. If necessary have a 1k resistor in series with the Csc to make the current loop a little bit faster.

#### Compensation of Voltage Loop

The adaptive voltage positioning is used in the computer applications to meet the load line requirements. Like current mode control, the adaptive voltage positioning loop introduces extra zero to the voltage loop and splits the double poles of the power stage, which make the voltage loop compensation much easier.

Resistors RFB and RDRP are chosen according to Equations (12) and (13), and the selection of compensation types depends on the capacitors used. For the applications using Electrolytic, Polymer or AL-Polymer capacitors, type II compensation shown in Figure 11 (a) is usually enough. While for the applications with only low ESR ceramic capacitors, type III compensation shown in Figure 11 (b) is preferred.





#### **Type II Compensation**

Determine the compensation at no load, the worst case condition. Assume the time constant of the resistor and capacitor across the output inductors matches that of the inductor, the crossover frequency of the voltage loop can be estimated by Equations (16), where CE and RCE are the equivalent capacitance and ESR of output capacitors respectively and RLE is the equivalent resistance of inductor DCR.

$$f_{C} = \frac{R_{DRP}}{2\pi * C_{E} * (G_{CS} * R_{FR} * R_{IE} - R_{CE})}$$
(16)

RCOMP and CCOMP have limited effect on the crossover frequency, and are used only to fine tune the crossover frequency and transient load response. Choose the desired crossover frequency fc1 around fc estimated by Equation (16) and determine RCOMP and CCOMP.

$$R_{COMP} = \frac{(2\pi * f_{C1})^2 * L_E * C_E * R_{FB}}{V_{IN} * F_M}$$
(17)

$$C_{COMP} = \frac{10 * \sqrt{L_E * C_E}}{R_{COMP}}$$
(18)

CCP1 is optional and may be needed in some applications to reduce the jitter caused by the high frequency noise. A ceramic capacitor between 10pF and 220pF is usually enough. In equation (17), VIN is the input voltage, FM is the PWM comparator gain (refer to equation (25)).

#### **Type III Compensation**

Determine the compensation at no load, the worst case condition. Assume the time constant of the resistor and capacitor across the output inductors matches that of the inductor, the crossover frequency of the voltage loop can be estimated by Equations (19).

$$f_{C} = \frac{R_{DRP}}{2\pi * C_{E} * G_{CS} * R_{FB} * R_{LE}}$$
(19)

Choose the desired crossover frequency fc1 around fc estimated by Equation (19). Select other components to ensure the slope of close loop gain is -20dB/Dec around the crossover frequency. Choose resistor RFB1 according to Equation (20), and determine CFB and CDRP from Equations (21) and (22).

$$R_{FB1} = \frac{1}{2} R_{FB}$$
 to  $R_{FB1} = \frac{2}{3} R_{FB}$  (20)

$$C_{FB} = \frac{1}{4\pi * f_{C1} * R_{FB1}}$$
(21)

$$C_{DRP} = \frac{(R_{FB} + R_{FB1}) * C_{FB}}{R_{DRP}}$$
(22)

RCOMP and CCOMP have limited effect on the crossover frequency, and are used only to fine tune the crossover frequency and transient load response. Determine RCOMP and CCOMP from Equations (23) and (24), where FM is the PWM comparator gain defined by Equation (25).

$$R_{COMP} = \frac{(2\pi * f_{C1})^2 * L_E * C_E * R_{FB}}{V_I * F_M}$$
(23)

$$C_{COMP} = \frac{10 * \sqrt{L_E * C_E}}{R_{COMP}}$$
(24)

$$F_{M} = \frac{V_{O}}{V_{I} * V_{RAMP}}$$
(25)

CCP1 is optional and may be needed in some applications to reduce the jitter caused by the high frequency noise. A ceramic capacitor between 10pF and 220pF is usually enough.

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## **DESIGN EXAMPLE**

#### IR3093 Demo Board for VRD10.1 Application

#### Specifications:

Input Voltage: VI=12 V DAC Voltage: VDAC=1.35 V No Load Output Voltage Offset: VO\_NLOFST=20 mV Output Current: IO=101 A DC Output Current Limit set point: ILIMIT=130 A Output Impedance: RO=1m $\Omega$ VCC Ready to VCC Power Good Delay: tVccPG=0-10mS Soft Start Time: tSS=2 mS Dynamic VID Down-Slope Slew Rate: SRDOWN=2.5mV/uS

#### Power Stage Design

Control IC: IR3093 Phase Number: n=3 Switching Frequency: fsw=300 kHz Output Inductors: L=0.25 uH, RL=0.65 mΩ Output Capacitors: C=0.007F, RcE=0.7 mΩ

#### **External Components**

#### **Oscillator Resistor Rosc**

Once the switching frequency is chosen, ROSC can be determined from the curve in this datasheet. For switching frequency of 300 kHz per phase, Choose ROSC= $30k\Omega$ 

#### Soft Start Capacitor Css

Calculate the soft start capacitor from the required soft start time 2mS.

$$C_{SS} = \frac{I_{CHG} * t_{SS}}{V_{O}} = \frac{60 * 10^{-6} * 2 * 10^{-3}}{1.35 - 20 * 10^{-3}} = 0.09 * 10^{-6} F$$
 Choose Css = 0.1 uF

With the selected Css value, we can calculate the following delay times:

The Over-Current fault latch delay time tOCDEL will be:

$$t_{OCDEL} = \frac{C_{SS} * \Delta V}{I_{DISCHG}} = \frac{0.1 * 10^{-6} * 0.25}{61 * 10^{-6}} = 0.4 mS$$

The soft start delay time is

$$t_{SSDEL} = \frac{C_{SS} * \Delta V}{I_{CHG}} = \frac{0.1 * 10^{-6} * 1.1}{60 * 10^{-6}} = 1.8mS$$

The power good delay time is

$$t_{v_{ccPG}} = \frac{C_{ss} * \Delta V}{I_{cHG}} = \frac{0.1 * 10^{-6} * (3.75 - 1.33 - 1.1)}{60 * 10^{-6}} = 2.2mS$$

#### **VDAC Slew Rate Programming Capacitor CDAC and Resistor RDAC**

From this data sheet, the sink current ISINK of VDAC pin corresponding to ROSC=30k $\Omega$  is 85uA. Calculate the VDAC down-slope slew-rate programming capacitor from the required down-slope slew rate.

$$C_{VDAC} = \frac{I_{SINK}}{SR_{DOWN}} = \frac{85 \times 10^{-6}}{2.5 \times 10^{-3} / 10^{-6}} = 34nF$$

Choose CVDAC = 33nF Calculate the programming resistor.

$$R_{DAC} = 0.5 + \frac{3.2 \times 10^{-15}}{C_{DAC}^{2}} = 0.5 + \frac{3.2 \times 10^{-15}}{(33 \times 10^{-9})^{2}} = 3.4\Omega$$

In practice slightly adjust RDAC to get desired slew rate.

#### **Over Current Setting Resistor ROCSET**

According to the spec, the output current limit set point  $I_{\text{LIMIT}} = 130A$ . The bias current IOCSET set by  $R_{\text{ROSC}}$  is around 40uA. Assume the maximum temperature  $T_{\text{L}}MAX = 120$  C, the room temperature TROOM=25 C, so

$$R_{L_{-MAX}} = 0.65 * 10^{-3} * [1 + 3850 * 10^{-6} * (120 - 25)] = 0.9m\Omega$$

Assume maximum IC temperature TIC\_MAX=110C, the minimum current sense amplifier gain can be calculated from Equation (11).

$$G_{CS_MIN} = 23.5 * [1 - 1400 * 10^{-6} * (110 - 25)] = 21$$

Using Equation (12) and (13) to calculate ROCSET:

$$\Delta I = \frac{Vo*(Vin - Vo)}{L*Vin*fsw} = \frac{1.33*(12 - 1.33)}{0.25*10^{-6}*12*300*10^{3}} = 15.8 \text{ A}$$

$$R_{OCSET} = \left[\left(\frac{I_{LIMIT}}{3} + \frac{\Delta I}{2}\right) * R_{L_{-MAX}}\right] * G_{CS_{-MIN}} / I_{OCSET} = \left[\left(\frac{130}{3} + \frac{15.8}{2}\right) * 0.9 * 10^{-3}\right] * 21/(40 * 10^{-6}) = 24.2k\Omega$$

Choose ROCSET =  $25 \text{ k}\Omega$ 

#### No Load Output Voltage Setting Resistor RFB and Adaptive Voltage Positioning Resistor RDRP

The value of the internal current source current IFB in the curve is 42uA according to  $R_{ROSC} = 30k\Omega$ .

$$R_{FB} = \frac{V_{O_-NLOFST}}{I_{FB}} = \frac{20*10^{-3}}{42*10^{-6}} = 476\Omega.$$
 Choose RFB = 499Ω

$$R_{DRP} = \frac{R_{FB} * R_{L_{-MAX}} * G_{CS_{-MIN}}}{n * R_{O}} = \frac{499 * 0.9 * 10^{-3} * 21}{3 * 1 * 10^{-3}} = 3.1k\Omega$$

Choose RDRP =  $3.09k\Omega$ 

#### Inductor Current Sensing Capacitor CCs and Resistors RCs1 and RCs2

Choose capacitor CCS = 0.22uF calculate RCS1

$$R_{CS1} = \frac{L/R_L}{C_{CS}} = \frac{0.25*10^{-6}/0.65*10^{-3}}{0.22*10^{-6}} = 1.8k\Omega$$
 Choose RCs1=2kΩ

#### Set BIASOUT voltage Resistor Rset

Bias current  $I_{\text{SETBIAS}}$  is around 160uA in this case. Set VBIASOUT around 8V to be gate drive voltage of MOSFETs.

$$R_{SET} = \frac{V_{BIASOUT} + 0.3}{I_{SETBIAS}} = \frac{8 + 0.3}{160 * 10^{-6}} = 51.9k\Omega$$

Choose RSET=51.1k $\Omega$ 

#### **Compensation of Voltage Loop**

AL-Polymer output capacitors are used in the design, and the crossover frequency of the voltage loop can be estimated as,

$$f_{C} = \frac{R_{DRP}}{2\pi * C_{E} * (G_{CS} * R_{FB} * R_{LE} - R_{CE})} = \frac{3.09 * 10^{3}}{2\pi * 0.007 * [23.5 * 499 * (0.65 * 10^{-3} / 3) - 0.7 * 10^{-3}]} = 28kHz$$

RCOMP and CCOMP are used to fine tune the crossover frequency and transient load response. Choose the desired crossover frequency fc1 (=30kHz) and determine RCOMP and CCOMP.

$$F_{M} = \frac{V_{O}}{V_{I} * V_{RAMP}} = \frac{1.33}{12 * 0.63} = 0.18$$

$$R_{COMP} = \frac{(2\pi * f_{C1})^{2} * L_{E} * C_{E} * R_{FB}}{V_{I} * F_{M}} = \frac{(2\pi * 30 * 10^{3})^{2} * (250 * 10^{-9} / 3) * 0.007 * 499}{12 * 0.18} = 5k\Omega$$

$$C_{COMP} = \frac{10 * \sqrt{L_{E} * C_{E}}}{R_{COMP}} = \frac{10 * \sqrt{(250 * 10^{-9} / 3) * 0.007}}{5 * 10^{3}} = 48nF$$

In practice, adjust RCOMP and CCOMP if need to get desired dynamic load response performance.

## MathCAD file to estimate the power dissipation of the IC

This Mathcad file step by step shows how to estimate the power dissipation of the IC.

#### **Initial Conditions:**

| No.of Phases:            | n := 3                                |                 |                              |           |      |
|--------------------------|---------------------------------------|-----------------|------------------------------|-----------|------|
| IC Supply Voltage:       | Vcc:= 12 (V)                          | , IC Supply C   | Current(quiescent):          | Icq := 38 | (mA) |
| Total High side Driver V | CCH supply current(qui                | escent):        | Iqh := $5 \cdot n \pmod{mA}$ |           |      |
| Total Low side Driver V  | CCL supply Current(quie               | escent):        | $Iql := 5 \cdot n  (mA)$     |           |      |
| Biasout Voltage:         | Vbias := 7.5 (V)                      |                 |                              |           |      |
| Switching Frequency pe   | r phase: fsw :=                       | 300 (kHz)       |                              |           |      |
| Thermal Impedance of I   | C: $\theta_{JA} := 27 \ (^{O}C/^{O})$ | W)              |                              |           |      |
| The data from the select | ed MOSFETs:                           |                 |                              |           |      |
| Control FET IR6623       | , Number of Control FE                | ET per phase:   | nc := 1                      |           |      |
| Control FET total ga     | te charge: Qgc :=                     | = 16 (nC)       |                              |           |      |
| Synchronous FET IF       | R6620, Number of sync                 | . FET per phase | e: ns := 1                   |           |      |
| Sync FET total gate      | charge: Qgs := 4                      | 45 (nC)         |                              |           |      |

#### **Power Dissipation:**

The IC will have less power dissipation if using external gate driver supply. For the worst case estimation, assuming using the bias regulator for all the gate drive supply voltage.

1. Quiescent Power dissipation

Total Quiescent Power Dissipation:

$$Pq := (Icq + Iqh + Iql) \cdot Vcc \cdot 10^{-5} \qquad Pq = 0.816 \quad (W)$$

2. The Power Loss to drive the gate of the MOSFETs

With the assumption of the low MOSFET gate resistances, most gate drive losses are dissipated in the driver circuit.

Pdrv := Vbias 
$$\cdot$$
 fsw  $\cdot 10^{3} \cdot n \cdot \left[ (nc \cdot Qgc + ns \cdot Qgs) \cdot 10^{-9} \right]$  Pdrv = 0.412 (W)

Where the  $Ig := fsw \cdot 10^3 \cdot n \cdot (nc \cdot Qgc + ns \cdot Qgs) \cdot 10^{-9}$  term in the equation gives the total average bias current required to drive all the MOSFETs.

3. The bias regulator Power Loss to supply driving the MOSFETs

$$Preg := (Vcc - Vbias) \cdot Ig \qquad Preg = 0.247 \quad (W)$$

4. Total Power Dissipation of the IC:

Pdiss := 
$$Pq + Pdrv + Preg$$
 Pdiss = 1.475 (W)

And the total Junction temperature rising is: Pdiss  $\cdot \theta_{JA} = 39.82$  (°C)

## **APPLICATION CIRCUIT - 3 PHASE OPTERON CONVERTER**

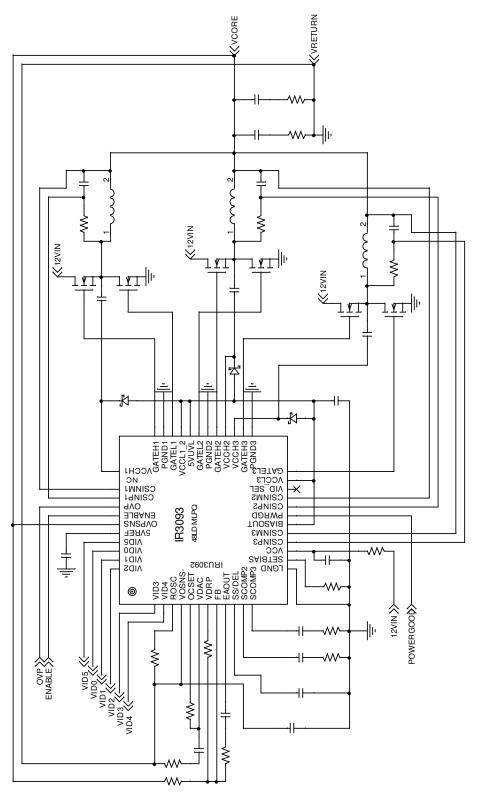


Figure 12. 12V Control, 12V Power Opteron Converter

## **APPLICATION CIRCUIT - 3 PHASE VR10.X CONVERTER**

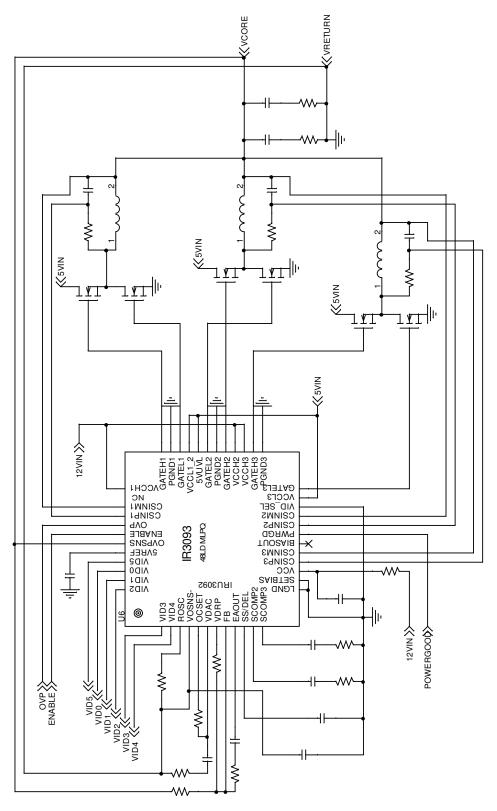


Figure 13. 12V Control, 5V Power, VR10 Converter

# LAYOUT GUIDELINES

The following layout guidelines are recommended to reduce the parasitic inductance and resistance of the PCB layout, therefore minimizing the noise coupled to the IC. Refer to the schematic in Figure 6 – System Diagram.

• Dedicate at least one inner layer of the PCB as power ground plane (PGND).

• The center pad of IC must be connected to ground plane (PGND) using the recommended via pattern shown in "Package Dimensions".

• The IC's PGND1, 2, 3 and LGND should connect to the center pad under IC.

• The following components must be grounded directly to the LGND pin on the IC using a ground plane on the component side of PCB: CSS, RSC2, RSC3, RSET, CVCC and C5VREF. The LGND should only be connected to ground plan on the center pad under IC

• Place the decoupling capacitors CVCC and CBIAS as close as possible to the VCC and VCCL1\_2, VCCL3 pins. The ground side of CBIAS should not be connected to LGND and it should directly grounded through vias.

• The following components should be placed as close as possible to the respective pins on the IC: RROSC, ROCSET, CDAC, RDAC, CSS, CSC2, RSC2, CSC3, RSC3, RSET.

• Place current sense capacitors CCS1, 2, 3 and resistors RCS1, 2, 3 as close as possible to CSINP1, 2, 3 pins of IC and route the two current sense signals in pairs connecting to the IC. The current sense signals should be located away from gate drive signals and switch nodes.

• Use Kelvin connections to route the current sense traces to each individual phase inductor, in order to achieve good current share between phases.

• Place the input decoupling capacitors closer to the drain of top MOSFET and the source of the bottom MOSFET. If possible, Use multiple smaller value ceramic caps instead of one big cap, or use low inductance type of ceramic cap, to reduce the parasitic inductance.

• Route the high current paths using wide and short traces or polygons. Use multiple vias for connections between layers.

- The symmetry of the following connections from phase to phase is important for proper operation:
- The Kelvin connections of the current sense signals to inductors.
- The gate drive signals from the IC to the MOSFETS.
- The polygon shape of switching nodes.

# PCB AND STENCIL DESIGN METHODOLOGY

- 7x7
- 48 Lead
- 0.5mm pitch MLPQ

See Figures 14-16.

PCB Metal Design (0.5mm Pitch Leads)

- 1. Lead land width should be equal to nominal part lead width. The minimum lead to lead spacing should be  $\ge 0.2$ mm to minimize shorting.
- Lead land length should be equal to maximum part lead length + 0.2 mm outboard extension + 0.05mm inboard extension. The outboard extension ensures a large and inspectable toe fillet, and the inboard extension will accommodate any part misalignment and ensure a fillet.
- Center pad land length and width should be = maximum part pad length and width. However, the minimum metal to metal spacing should be ≥ 0.17mm (2 oz. Copper, ≥ 0.23mm for 3 oz. Copper and ≥ 0.1mm for 1 oz. Copper)
- 4. Sixteen 0.30mm diameter vias shall be placed in the pad land spaced at 1.2mm, and connected to ground to minimize the noise effect on the IC, and to transfer heat to the PCB.

PCB Solder Resist Design (0.5mm Pitch Leads)

- 1. Lead lands. The solder resist should be pulled away from the metal lead lands by a minimum of 0.060mm. The solder resist mis-alignment is a maximum of 0.050mm and it is recommended that the lead lands are all NSMD. Therefore pulling the S/R 0.060mm will always ensure NSMD pads.
- The minimum solder resist width is 0.13mm, therefore it is recommended that the solder resist is completely removed from between the lead lands forming a single opening for each "group" of lead lands.
- 3. At the inside corner of the solder resist where the lead land groups meet, it is recommended to provide a fillet so a solder resist width of  $\ge 0.17$ mm remains.
- 4. Land Pad. The land pad should be SMD, with a minimum overlap of the solder resist onto the copper of 0.060mm to accommodate solder resist mis-alignment. In 0.5mm pitch cases it is allowable to have the solder resist opening for the land pad to be smaller than the part pad.
- 5. Ensure that the solder resist in-between the lead lands and the pad land is  $\geq$  0.15mm due to the high aspect ratio of the solder resist strip separating the lead lands from the pad land.
- 6. The single via in the land pad should be tented with solder resist 0.4mm diameter, or 0.1mm larger than the diameter of the via.

Stencil Design (0.5mm Pitch Leads)

- The stencil apertures for the lead lands should be approximately 80% of the area of the lead lands. Reducing the amount of solder deposited will minimize the occurrence of lead shorts. Since for 0.5mm pitch devices the leads are only 0.25mm wide, the stencil apertures should not be made narrower; openings in stencils < 0.25mm wide are difficult to maintain repeatable solder release.
- 2. The stencil lead land apertures should therefore be shortened in length by 80% and centered on the lead land.
- 3. The center land pad aperture should be striped with 0.25mm wide openings and spaces to deposit approximately 50% area of solder on the center pad. If too much solder is deposited on the center land pad the part will float and the lead lands will be open.
- 4. The maximum length and width of the center land pad stencil aperture should be equal to the solder resist opening minus an annular 0.2mm pull back to decrease the incidence of shorting the center land to the lead lands when the part is pushed into the solder paste.

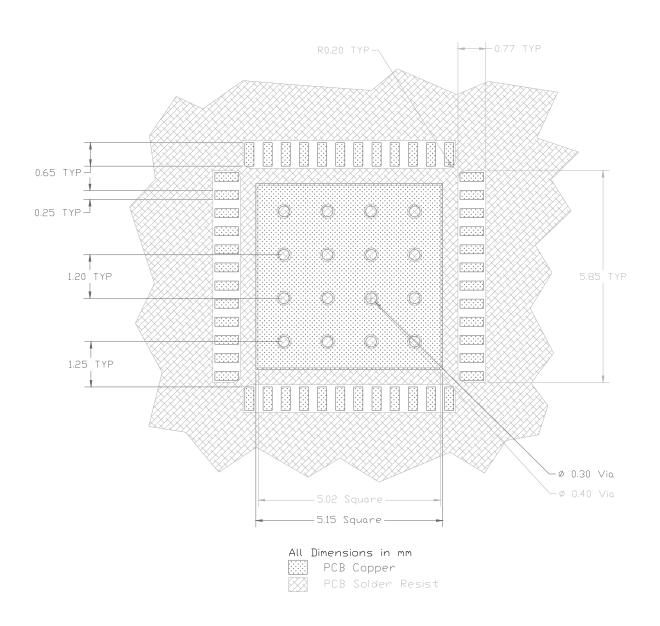


Figure 14. PCB metal and solder resist.

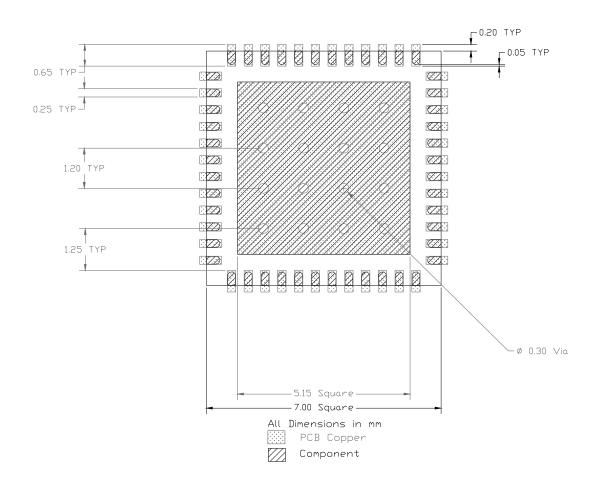
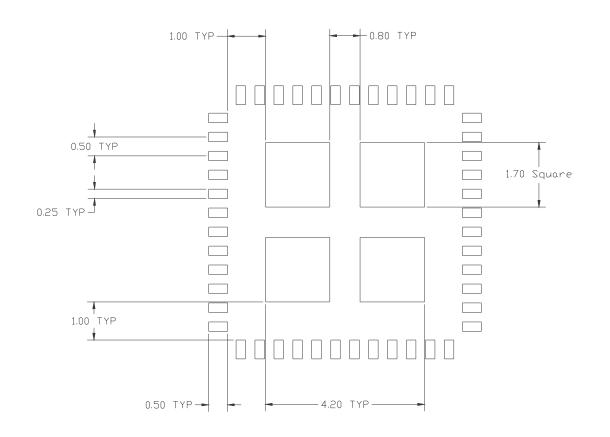


Figure 15. PCB metal and component placement.



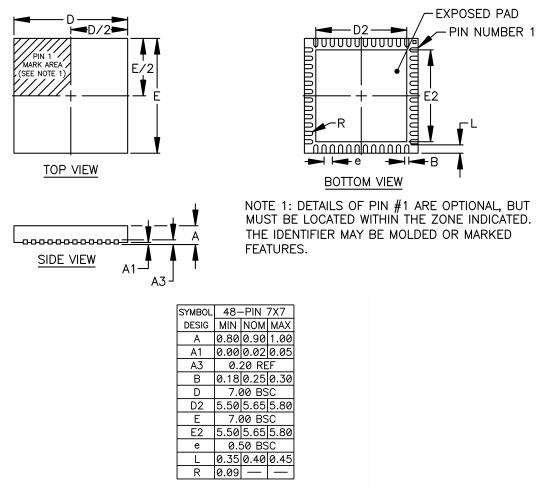
Stencil Aperture

All Dimensions in mm

Figure 16. Stencil design.

IR3093PbF

# PACKAGE DIMENSIONS



NOTE: ALL DIMENSIONS ARE IN MILLMETERS.

Data and specifications subject to change without notice. This product has been designed and qualified for the Consumer market. Qualification Standards can be found on IR's Web site.



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